

Thermal analysis and crystal growth of doped Nb₂O₅

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Abstract

The systems Nb₂O₅–Ta₂O₅ and Nb₂O₅–V₂O₅ were investigated using thermal analysis, X-ray powder diffraction and thermodynamic simulations. Solid solution formation is possible for both systems; furthermore, both contain one intermediate compound, VNb₉O₂₅ or Ta₂Nb₄O₁₅, respectively. Phase relationships for pure niobium(V)-oxide and tantalum(V)-oxide were studied under ambient pressure. It was found that both compounds can occur in two stable solid modifications. For niobium(V)-oxide this are the monoclinic high-temperature modification (H-Nb₂O₅) and an orthorhombic low-temperature modification (T-Nb₂O₅) and for tantalum(V)-oxide a tetragonal high-temperature form (α -Ta₂O₅) and an orthorhombic low-temperature form (β -Ta₂O₅). Based on these results, crystal growth experiments with various compositions from both systems were carried out using the optical floating zone (OFZ) technique.

Keywords: A1. doping, A1. phase diagrams, A2. growth from melt, B1. niobates, B2. dielectric materials

1. Introduction

The oxides of niobium form a complex system consisting of numerous polymorphic phases. Being able to adopt different structures, niobium oxides possess interesting properties, which allow their application in science and technology. Besides the usage as solid electrolyte capacitor or complementary metal oxide semiconductors, the photochromic switching of niobium(V)-oxide coupled with the ability to transform into a conductive suboxide offers the potential to use these materials as photoelectrodes in solar cells [1, 2, 3, 4, 5].

Another field of current research is the resistive switching behavior of Nb₂O₅, which was first described in 1965 by Hiatt and Hickmott [6]. This property of niobium(V)-oxide could allow the construction of memristors and their application as non-volatile memory devices [7, 8, 9]. For the production of functioning memristors, a detailed knowledge of the structural changes and other processes will be necessary, that take place during the setting of the resistance. To investigate this issue, the study of homoepitaxial niobium-oxide layers seems promising. However, substrate single crystals of niobium(V)-oxide are not commercially available.

The variety of different modifications that can occur for niobium(V)-oxide makes bulk crystal growth rather challenging. Nevertheless, Shindo and Komatsu [10] succeeded in growing undoped H-Nb₂O₅ crystals with diameters of about 6 mm and lengths of several centimeters. In the

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literature, contradictory information can be found on the structure and stability of the various modifications. While Orr and King [11, 12] describe a single monoclinic modification, which exists from room temperature to the melting point without performing a phase transition, Brauer and many other authors observe several transitions between different modifications [13, 14, 15, 16, 17, 18].

In this paper the two systems $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$ and $\text{Nb}_2\text{O}_5\text{-Ta}_2\text{O}_5$ are investigated using different techniques of thermal analysis and X-ray powder diffraction, supported by a thermodynamic assessment of both systems. The aim of this study is to clarify phase equilibria of the pure oxides, as well as the two pseudo-binary systems. Additionally, an attempt was made to grow first doped Nb_2O_5 -crystals using the optical floating zone technique. In this context it is of particular interest whether mixed-crystal formation of niobium(V)-oxide with the two oxides Ta_2O_5 or V_2O_5 is possible and whether single-crystal growth of niobium(V)-oxide can be stabilized by doping with the oxides of group five of the periodic table.

2. Experimental

For the preparation of all samples, as well as for the feed-rods and seed-rods for crystal growth, the following powdered chemicals were used: Nb_2O_5 (H.C. Starck, purity 99.995%), Ta_2O_5 (Fox-Chemicals GmbH, 99.99%) and V_2O_5 (Aran Isles Chemicals Inc., 99.99%).

Pure oxides and mixtures of different composition from the systems $\text{Nb}_2\text{O}_5\text{-Ta}_2\text{O}_5$ and $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$ were investigated by differential thermal analysis (DTA) with simultaneous thermogravimetry (TG). For this purpose, the chemicals were weighed in varying proportions, mixed and analyzed using a NETZSCH STA 449C Jupiter thermal analyzer. A DTA/TG sample carrier with Pt/Pt90Rh10 thermocouples and platinum crucibles allowed measurements up to 1650°C in a flowing mixture of 20 ml/min argon and 20 ml/min oxygen. Only for the determination of the melting point of pure tantalum(V)-oxide high-temperature DTA/TG measurements were performed in a NETZSCH STA 429C analyzer with W/Re thermocouples and tungsten crucibles in static helium atmosphere.

Each DTA/TG measurement consisted of three heating/cooling cycles with rates of 10 K/min. Between the individual heating segments, the samples were cooled to 40°C . The maximum temperature for each sample was chosen in such a way that the liquidus temperature was surpassed. The first heating was used to homogenize the sample by melting the substance mixture. Most signals for the evaluation of the measurements were taken from the second heating cycle, while the third heating segment was used to assess the reproducibility of the signals. In all measurements no significant mass changes were detected, so that a reduction of the investigated substances by oxygen release during the heating phase can be excluded.

The different crystal phases and modifications were characterized by X-ray powder diffraction with an XRD 3003 TT (GE Inspection Technologies), which has Bragg-Brentano geometry with scintillation detector. These measurements were carried out using the $\text{Cu K}\alpha_1$ radiation with a wavelength of $\lambda = 154.06\text{ pm}$. For that purpose, powder samples of the pure oxides and some mixtures from the binary systems $\text{Nb}_2\text{O}_5\text{-Ta}_2\text{O}_5$ and $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$ were heated to various temperatures with a heating rate of 10 K/min and sintered for several hours using NETZSCH STA 449C Jupiter and NETZSCH STA 409C furnaces and Pt crucibles (for the exact conditions see table 1). The samples were then ground in a mortar and analyzed by X-ray powder diffraction.

Crystal growth experiments of doped niobium(V)-oxide were carried out in an optical floating zone (OFZ) furnace FZ-T-10000-H-VII-VPO-PC (Crystal System Corporation) with four ellipsoidal mirrors and four 1500 W halogen bulbs. Best results were achieved using a pre-molten feed-rod, a growth rate of 6 mm/h and a rotation rate of 30 rpm. Flowing dried air (2 l/min) under ambient pressure was the growth atmosphere.

Table 1: Composition and sintering conditions of the samples investigated with XRD (holding temperature and holding time as well as cooling rate). All samples were heated at a rate of 10 K/min. In addition, the untreated oxides were used to investigate the room temperature modifications. These samples are referred to as Nb1 (untreated Nb₂O₅), Ta1 (Ta₂O₅) and V1 (V₂O₅).

Name	Substance	$x(\text{Nb}_2\text{O}_5)$	Temp. [°C]	Time [h]	Cooling [K/min]
Nb2	Nb ₂ O ₅	1	720	50	10
			550	50	10
Nb3	Nb ₂ O ₅	1	1460	20	30
Ta2	Ta ₂ O ₅	0	1460	20	30
Ta3	Ta ₂ O ₅	0	1550	15	60
V2	V ₂ O ₅	0	600	20	40
NbV1	Nb ₂ O ₅ + V ₂ O ₅	0.96	700	20	30
NbV2	Nb ₂ O ₅ + V ₂ O ₅	0.88	700	20	30
NbTa1	Nb ₂ O ₅ + Ta ₂ O ₅	0.95	1460	20	30
NbTa2	Nb ₂ O ₅ + Ta ₂ O ₅	0.86	1460	20	30

3. Results and Discussion

3.1. Phases of the pure oxides

Fig. 1 shows DTA curves of three subsequent heating segments with Nb₂O₅ or Ta₂O₅, respectively. For Nb₂O₅, only the melting point $T_f = (1484 \pm 4)^\circ\text{C}$ is obvious as a sharp, endothermic peak; no further signals are visible during heating and cooling. The somewhat higher onset of the melting peak during the first heating might result from a loose packing of the powder sample with consequently poor thermal contact to the crucible wall. Literature data on the melting point of Nb₂O₅ are largely inconsistent: values of 1465 °C [19], 1479 °C [20], 1491 °C [21] and 1512 °C [22] are published. The melting point observed in this work is within the range defined by the literature.

In contrast to the DTA measurements, X-ray powder diffraction of pure niobium(V)-oxide reveals the presence of two modifications. As shown in Fig. 2 (left side), all reflections observed in the diffractograms of samples Nb1 and Nb3 can be fully explained by a monoclinic phase, which is consistent with the high-temperature modification H-Nb₂O₅ [13, 23]. Sample Nb2 has additional signals that can be assigned to an orthorhombic low-temperature modification T-Nb₂O₅ [13, 24]. By long-term sintering for 50 hours at temperatures around 700 °C, it was apparently possible to achieve partial transition to this low-temperature modification, whereas the raw sample Nb1 consists of the H-Nb₂O₅ phase which is obviously metastable.

Contrary to the current work, conversion from H-Nb₂O₅ to T-Nb₂O₅ could not be observed by Brauer. He described that even after 12 days of sintering at 850 °C only the pure H-modification was present [13], which excludes a transition beyond this temperature. Also Holtzberg et al. and Waring et al. found no reversibility in various annealing experiments [21, 25]. Therefore, Waring concluded that the T-modification was a metastable state. This conclusion cannot be supported in the present work. Rather, it is assumed that the transformation is a kinetically inhibited reaction, so that the thermodynamic minimum can only be reached by long-term sintering.

The DTA curves of tantalum(V)-oxide in Fig. 1 (bottom) show several phase transitions up to 1640 °C. During first heating, a single endothermic signal appears at 1469 °C, while other endothermic signals at 341 °C and 951 °C appear during the following heating segments. The melting point is beyond the temperature range of this measurement, but measurements in the STA 429 showed $T_f = (1883 \pm 20)^\circ\text{C}$ (Fig. A.1 in the supplementary material), which is in good agreement with literature data $T_f = 1875^\circ\text{C}$ [29] and 1878 °C [22].

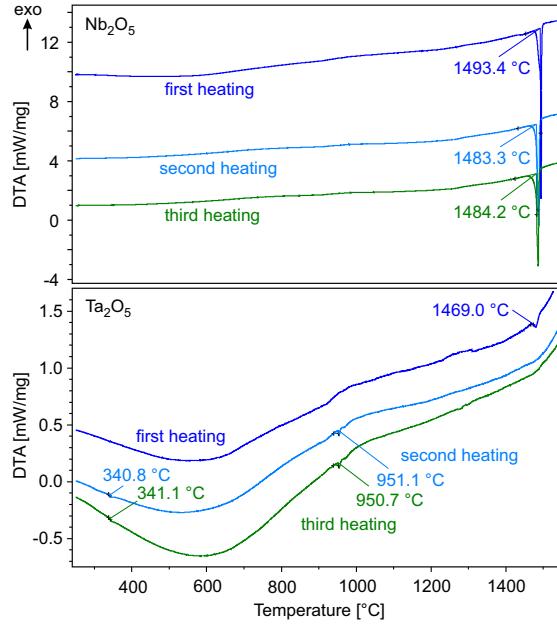


Figure 1: Typical DTA heating curves of a complete measurement cycle with three heating segments from Nb_2O_5 and Ta_2O_5 . The temperature at which a phase transition occurs can be determined as the onset of the signals.

Furthermore, the X-ray powder diffraction measurements of tantalum(V)-oxide reveal the presence of two modifications (see Fig. 2). While the diffractograms of the samples Ta1 and Ta2 show only the orthorhombic low-temperature modification [26], the X-ray diffractogram of sample Ta3 differs significantly from the previous ones. The signals of this diffractogram can be assigned to a triclinic crystal structure [27]. It should be noted that only the annealing temperature of Ta3 (Tab. 1) is beyond the phase transition that was detected during the first heating of Ta_2O_5 (Fig. 1).

According to the literature, tantalum oxide exists in two polymorphic modifications α - Ta_2O_5 (tetragonal high-temperature form) and β - Ta_2O_5 (orthorhombic low-temperature form). However, there is some disagreement in the phase transition temperature. Lagergren et al. report the existence of a high-temperature modification above $T_t = 1320^\circ\text{C}$ [30], while Waring et al. observe this modification only above 1360°C [31]. Füglein et al. found the transition from β - Ta_2O_5 to α - Ta_2O_5 at 1482°C [32], which is in fairly good agreement with the DTA results from this work. In addition to these two thermodynamically stable modifications, tantalum(V)-oxide has several metastable structures [31, 32, 33, 34]. Waring et al. observe a tetragonal modification, which on cooling first changes to a monoclinic and then to a triclinic modification [31]. Recently, the same results were obtained by Füglein et al. [32].

Based on the observations of Waring and Füglein, the present work assumes that α - Ta_2O_5 and β - Ta_2O_5 are the only thermodynamically stable solid modifications, with $T_t = 1469^\circ\text{C}$, as shown during the first heating of Ta_2O_5 in Fig. 1. No indications for the back transformation $\alpha \rightarrow \beta$ were found in the DTA cooling curves, which indicates that the high- T form can exist metastable also below T_t . However, this metastable α - Ta_2O_5 tends to transform to the metastable modifications α' and α'' upon cooling. The room temperature metastable α'' -form has then a triclinic crystal structure, which is in agreement with the results of the X-ray powder diffraction spectrum of sample Ta3 in Fig. 2. The DTA peaks at 341°C and 951°C (Fig. 1) results from transformations

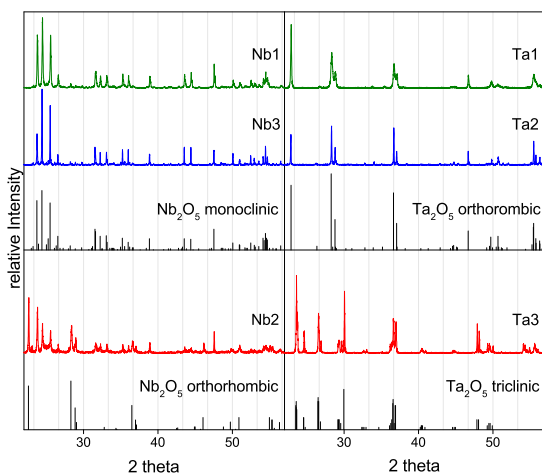


Figure 2: Left: X-ray diffractograms of Nb_2O_5 compared to literature data (black curves) for monoclinic H- Nb_2O_5 [23] and orthorhombic T- Nb_2O_5 [24]. By sintering at temperatures around 700°C , it was possible to achieve the transition to the low-temperature modification. Right: X-ray diffractograms of Ta_2O_5 compared to literature data for orthorhombic β - Ta_2O_5 [26] and triclinic α' - Ta_2O_5 [27], which is a metastable low-temperature form of the tetragonal α - Ta_2O_5 [28].

between the metastable modifications of Ta_2O_5 .

Consistent with the literature, for V_2O_5 only one stable modification was found by X-ray powder diffraction. Also, the DTA measurements of vanadium(V)-oxide show only one sharp, endothermic signal at 668°C , which can be attributed to the melting point (Fig. A.2). This value is in very good agreement with the literature where $T_f = 669.8^\circ\text{C}$ is given [22].

3.2. The binary system Nb_2O_5 - V_2O_5

The system Nb_2O_5 - V_2O_5 was first investigated by Waring and Roth in 1964 [35]. Basic features of their phase diagram could be confirmed by the current results that are shown in Fig. 3. This diagram is set up by the components V_2O_5 , Nb_2O_5 (H- and T-phase) and by an intermediate compound $\text{VNb}_9\text{O}_{25}$. In addition to the previous report [35], a transition between low- and high- T phases s1 and s2 of $\text{VNb}_9\text{O}_{25}$ was found in the current study, leading to strong DTA peaks near 990°C . Other DTA peaks that occur at constant temperatures over a wide concentration range result from the eutectic close to V_2O_5 ($T_{\text{eut}} = 663^\circ\text{C}$) and from the peritectic decomposition of $\text{VNb}_9\text{O}_{25}$ at $T_{\text{per}} = 1375^\circ\text{C}$. This peak appears only for compositions $0.75 \leq x(\text{Nb}_2\text{O}_5) \leq 0.9$; the lower limit defines the peritectic point, and the upper limit defines the solubility limit of V_2O_5 in the H- Nb_2O_5 (ss) solid solution phase.

Waring and Roth describe a larger series of intermediate compounds, e.g. $\text{V}_2\text{Nb}_{23}\text{O}_{62} = \frac{1}{2}\text{V}_4\text{Nb}_{46}\text{O}_{124}$ in the niobium oxide-rich part of the phase diagram [35]. These results cannot be confirmed in the present work, and only $\text{VNb}_9\text{O}_{25}$ was found. This observation is in agreement with other authors [20, 36, 37, 38, 39]. Schadow et al. were able to isolate only one stable compound by studying the system using chemical transport reactions [20, 36]. The phase diagram constructed on the basis of these results shows correspondingly great agreement with that of the present work. The additional intermediate compounds discovered by Waring and Roth actually have a lower oxygen content and are therefore not part of the examined system [39]. For the example mentioned above one finds e.g. $\text{V}_4\text{Nb}_{46}\text{O}_{124} = 2\text{V}_2\text{O}_5 \cdot 22\text{Nb}_2\text{O}_5 \cdot \text{Nb}_2\text{O}_4$.

Fig. 3 summarizes DTA results of all measurements performed in the system $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$ together with a thermodynamic assessment using the software FactSage 7.1, a program for determining the equilibrium state in chemical systems from $G(T, x)$ functions for the different phases (x – molar fractions). To calculate this graph, data for the solids were taken from the FactSage databases [22] and modified to match the experimental observations. For V_2O_5 , only the transition from the solid to the liquid phase was defined at $T_f = 669.8^\circ\text{C}$, while the FactSage data for Nb_2O_5 were supplemented by another solid phase such that it has two solid and one liquid phase. Since the transformation from the low-temperature phase to the high-temperature phase could not be determined in the present work, this value was set to $T_t = 800^\circ\text{C}$ according to Shafer and Roy [19]. Additionally, the intermediate $\text{VNb}_9\text{O}_{25} = \frac{1}{2}(\text{V}_2\text{O}_5 \cdot 9\text{Nb}_2\text{O}_5)$ was introduced using weighted data from the component oxides. In order to include mixed phases in the calculations, two solutions were generated. These are on the one hand the solid solution in the high-temperature phase of Nb_2O_5 and on the other hand the melt.

A suitable model for the excess Gibbs free energy of the melt was found by Redlich-Kister polynomials [40, 41] for a binary system of components A and B.

$$G^{ex} = x_A x_B \cdot \sum_{j=0}^N L_j (x_A - x_B)^j \quad (1)$$

Here, x_A and x_B describe the mole fractions of the components and L_j is the j -th interaction parameter of the two components. All thermodynamic data of the components used for the simulations as well as the adjusted interaction parameters are given in the tables A.1-A.5 in the supplementary materials.

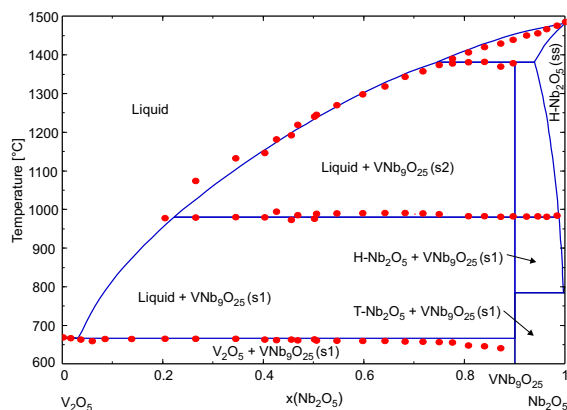


Figure 3: DTA signals (dots) and thermodynamic assessment of the system $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$.

The determined marginal solubility of V_2O_5 in Nb_2O_5 is in agreement with the work of Waring and Roth [35]; whereas Schadow et al. [20] found no significant formation of a solid solution. It was noted there, however, that solubility could not be accurately determined by the methods used by these authors and therefore, the lack of solubility in [20] is not considered to contradict the present work. The dissolution of V_2O_5 in Nb_2O_5 is confirmed also by the X-ray diffractograms of the mixture samples NbV1 and NbV2. While NbV1 shows only reflections that can be assigned to pure Nb_2O_5 , all reflections occurring in the diffractogram of the sample NbV2 can be interpreted using literature data from $\text{VNb}_9\text{O}_{25}$ (see Figs. A.3 and A.4). Since no reflections of the intermediate are found in the sample NbV1, it can be assumed that a mixed crystal is formed and therefore Nb_2O_5 can dissolve at least 4% V_2O_5 .

3.3. The binary system Nb_2O_5 - Ta_2O_5

Already Holtzberg et al. and Mohanty et al. [42, 43] reported the phase diagram of the system Nb_2O_5 - Ta_2O_5 . Both papers assumed that niobium(V)-oxide is stable in the H-modification over the entire range of the solid phase, which is in contrast to the current study (see section 3.1). However, the phase diagrams differ little from the diagram determined in this work, because the H-/T-transformation of Nb_2O_5 (see previous section 3.2) takes place at $T_t = 800^\circ\text{C}$, which is below the displayed temperature range.

Fig. 4 summarizes the DTA signals of all measurements performed in the system Nb_2O_5 - Ta_2O_5 , where the temperatures of the detected signals are plotted against the composition of the examined sample. Again, thermodynamic calculations were carried out using FactSage 7.1 data [22] with Redlich-Kister polynomials. For both pure components, the thermodynamic data were supplemented with an additional solid phase. For this purpose, the α/β transition temperature $T_t = 1469^\circ\text{C}$ for Ta_2O_5 was used (section 3.1). Besides, an intermediate compound $Ta_2Nb_4O_{15}$ was introduced. Two solid solutions between the β - or α -modifications of Ta_2O_5 and Nb_2O_5 describe the edge solubility in the tantalum-rich part of the diagram. Furthermore, a solution of H- Nb_2O_5 and Ta_2O_5 describes the edge solubility in the niobium-rich part of the diagram. Finally, a solution of the two liquid phases was defined, which represents the melt in the investigated system (see tables A.1-A.5 in the supplementary materials).

The phase diagram of the system Nb_2O_5 - Ta_2O_5 shows strongly pronounced edge solubilities of niobium(V)-oxide and tantalum(V)-oxide, which are interrupted only in the concentration range $0.3 \lesssim x(Ta_2O_5) \lesssim 0.6$. The intermediate compound $Ta_2Nb_4O_{15}$ is stable only in a narrow T -range; DTA data suggest that this compound has a phase transition s1/s2 at about 1560°C and decomposes peritectically at 1590°C . For Ta_2O_5 concentrations $x < 0.2$, the upper T -limit of the H- Nb_2O_5 phase field is the solidus of this phase, and the onset of melting leads to strong DTA peaks there. For $x > 0.2$, however, the phase field is limited by the beginning formation of $Ta_2Nb_4O_{15}$ (s1) from the H- $(Nb_{1-x}Ta_x)_2O_5$ solid solution. Because in this process exclusively solid phases are involved, the enthalpy change is significantly smaller than for the melting process at $x < 0.2$, and hence the corresponding DTA effect is weak. The existence of single phase H- Nb_2O_5 (ss) below these phase boundaries could be confirmed by X-ray diffraction of NbTa1 ($x(Ta_2O_5) = 0.05$) and NbTa2 ($x(Ta_2O_5) = 0.14$), respectively (Tab. 1 and Fig. A.3).

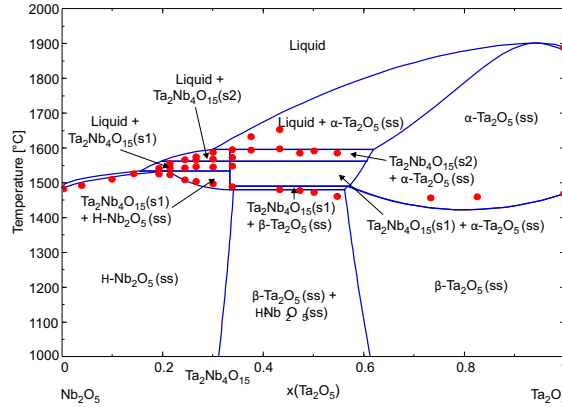


Figure 4: Summary of the DTA signals of various mixtures in the system Nb_2O_5 - Ta_2O_5 (dots) and thermodynamic assessment.

The recent studies [42, 43] described the limits of the solubility gap β - Ta_2O_5 +H- Nb_2O_5 by vertical lines; in contrast they are described by inclined curves in the present work (Fig. 4).

However, this course of the solubility limits seems more reasonable, since usually the solubility increases with T [44]. The phase transition temperature of pure Ta_2O_5 , $T_t = 1469^\circ\text{C}$ of the current study, is more than 100 K higher, compared to recent studies [42, 43] (see section 3.1).

The intermediate compound $\text{Ta}_2\text{Nb}_4\text{O}_{15}$ was first discovered by Holtzberg et al. [42] and then crystallographically analyzed by Ganesh et al. [45]. While Holtzberg was able to observe this compound at temperatures above 1450°C , Ganesh describes that the compound could already be synthesized at temperatures of 1400°C [45]. Accordingly, the formation temperature of $\text{Ta}_2\text{Nb}_4\text{O}_{15}$ in the phase diagram of Mohanty et al. is 1390°C [43]. In the present work, this compound was not separately investigated. However, the lowermost DTA effects near 1480°C around $x(\text{Ta}_2\text{O}_5) = \frac{1}{3}$ indicate, that the stability range of $\text{Ta}_2\text{Nb}_4\text{O}_{15}$ does not extend to significantly lower temperatures.

In contrast to the work of Mohanty, in this work the phase width of the intermediate compound was disregarded. Here, a small solubility for excess Nb_2O_5 and/or Ta_2O_5 cannot be excluded. Since the phase width could not be verified in this study, no further solutions were created for this compound during the thermodynamic simulations. However a phase transformation of this compound is detected using the DTA measurements and the DTA curves show a slight, monotonous increase in the transition temperature, which could be an indication for some phase width (a few per cent) of the intermediate compound.

Another peculiarity of the calculated phase diagram is the occurrence of an azeotropic point in the solid-liquid phase boundary in the tantalum-rich region of the diagram, resulting from the $G^{ex}(T, x)$ functions of the corresponding phases. None of the phase diagrams described in the literature contains such a point, but it can neither be refuted nor confirmed on the basis of the experimental data.

3.4. Crystal growth of doped Nb_2O_5

The thermodynamic investigations of the systems $\text{Nb}_2\text{O}_5\text{--V}_2\text{O}_5$ and $\text{Nb}_2\text{O}_5\text{--Ta}_2\text{O}_5$ proved significant solubility of Nb_2O_5 for vanadium(V)-oxide and especially for tantalum(V)-oxide. Therefore, it should be possible to grow niobium oxide crystals that are doped with V_2O_5 or Ta_2O_5 , respectively. Crystal growth experiments were carried out by optical floating zone technique, starting from feed-rods with 1–5 mol-% of the dopant. Within the scope of the present work it was possible to grow multicrystalline niobium(V)-oxide crystals with lengths up to 5 cm and diameters of about 1 cm. By cutting these crystals, single crystalline samples with lengths of about 6 mm could be obtained for $\text{Ta}:\text{Nb}_2\text{O}_5$, and with lengths of 10 mm for $\text{V}:\text{Nb}_2\text{O}_5$ (Fig. 5).

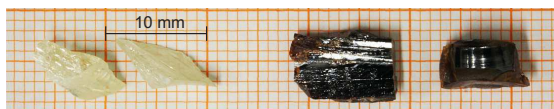


Figure 5: Left: $\text{Ta}:\text{Nb}_2\text{O}_5$ crystals with $x(\text{Ta}_2\text{O}_5) = 0.03$. Right: $\text{V}:\text{Nb}_2\text{O}_5$ crystals with $x(\text{V}_2\text{O}_5) = 0.01$.

The crystal growth process was typically associated with the formation of a solid “crown” and/or the appearance of “noses” at the transition from the feed rod into the molten zone. This atypical melting/solidification characteristics close to the seed resulted in a particular technical challenge, since the progressive growth of these features consumed a fraction of the melt and additionally hampered the heat input towards the residual melt. This effect appeared cyclically (at a longer time scale), and was often followed by a sudden increase in melt volume during melting of the “crown” or “noses” and sometimes resulted in demolition of the molten zone (Fig. 6).

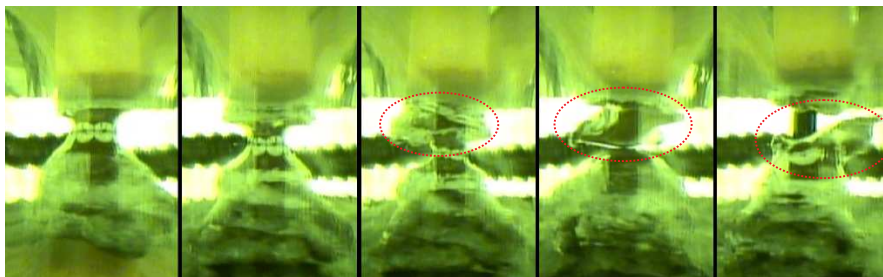


Figure 6: The formation of a “crown” during crystal growth of doped Nb_2O_5 crystals leads to unstable growth conditions and often to the destruction of the melt zone.

Within the scope of the present work it was not possible to eliminate the crown formation, but conditions could be found under which it was minimized. These include the use of pre-molten feed-rods and the application of higher light fluxes. In crystal growth, heat conduction plays a major role within the growing crystal and its environment [46, 47]. For continuous crystallization, stable flow of heat through the crystal is required. Additionally, the uniform melting of the starting material requires a homogeneous heat conduction within the feed-rod. Here pre-molten feed-rods seem to be superior with respect to feed-rods that were prepared by a conventional ceramic route. One possible origin of the crown formation could be an uneven heat input to various areas of the feed rod, which causes some areas to be heated more than others. Melting of the warmer regions would then lead to the formation of the observed crown structure.

4. Summary and conclusions

A thermodynamic assessment of the two systems $\text{Nb}_2\text{O}_5\text{-Ta}_2\text{O}_5$ and $\text{Nb}_2\text{O}_5\text{-V}_2\text{O}_5$ was carried out using thermal analysis and X-ray powder diffraction. The results showed that mixed-crystal formation is possible between Nb_2O_5 and vanadium(V)-oxide as well as Nb_2O_5 and tantalum(V)-oxide. Therefore, the phase diagrams of both systems have a marginal solubility of niobium(V)-oxide, which allows the growth of doped crystals and it was possible to obtain $\text{Ta:Nb}_2\text{O}_5$ as well as $\text{V:Nb}_2\text{O}_5$ single crystals with a size of up to 10 mm.

Despite the partially stable crystal growth, the resulting crystals always had cracks. In order to optimize the growth conditions, the use of an afterheater or the reduction of the growth rate [10] could be considered. It should be noted, however, that with a sufficiently long hold time, the kinetically inhibited phase transformation from $\text{H-Nb}_2\text{O}_5$ (which crystallizes first) to the low-temperature modification $\text{T-Nb}_2\text{O}_5$ can occur.

A particular challenge in the crystal growth of doped Nb_2O_5 is the formation of a “crown” at the transition from the feed-rod to the molten zone, resulting in unstable growth conditions. About the cause of this crown formation can only be speculated at the current time. Since only very few observations on such a behavior are described in the literature [48], further investigations in this area are necessary. One potential solution of this issue could be the usage of lamps with narrower filament sizes to reduce the height of the illuminated area.

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References

- [1] Y. Qiu, D. Smyth, J. Kimmel, The stabilization of niobium-based solid electrolyte capacitors, *Active and Passive Electronic Components* 25 (2002) 201–209. doi:<http://dx.doi.org/10.1080/08827510212343>.
- [2] V. Augustyn, J. Come, M. A. Lowe, J. W. Kim, P.-L. Taberna, S. H. Tolbert, H. D. Abruña, P. Simon, B. Dunn, High-rate electrochemical energy storage through Li^+ intercalation pseudocapacitance, *Nature Materials* 12 (2013) 518–522. doi:[10.1038/nmat3601](https://doi.org/10.1038/nmat3601).
- [3] K. Kukli, M. Ritala, M. Leskelä, Development of dielectric properties of niobium oxide, tantalum oxide, and aluminum oxide based nanolayered materials, *J. Electrochem. Soc.* 148 (2001) F35–F41. doi:[10.1149/1.1343106](https://doi.org/10.1149/1.1343106).
- [4] A. Le Viet, R. Jose, M. V. Reddy, B. V. R. Chowdari, S. Ramakrishna, Nb_2O_5 photoelectrodes for dye-sensitized solar cells: Choice of the polymorph, *J. Phys. Chem. C* 114 (2010) 21795–21800. doi:[10.1021/jp106515k](https://doi.org/10.1021/jp106515k).
- [5] T. Ohsawa, J. Okubo, T. Suzuki, H. Kumigashira, M. Oshima, T. Hitosugi, An n-type transparent conducting oxide: $\text{Nb}_{12}\text{O}_{29}$, *J. Phys. Chem. C* 115 (2011) 16625–16629. doi:[10.1021/jp203021u](https://doi.org/10.1021/jp203021u).
- [6] W. R. Hiatt, T. W. Hickmott, Bistable switching in niobium oxide diodes, *Appl. Phys. Lett.* 6 (1965) 106–108. doi:[10.1063/1.1754187](https://doi.org/10.1063/1.1754187).
- [7] H. Mähne, L. Berger, D. Martin, V. Klemm, S. Slesazeck, S. Jakschik, D. Rafaja, T. Mikolajick, Filamentary resistive switching in amorphous and polycrystalline Nb_2O_5 thin films, *Solid-State Electron.* 72 (2012) 73–77. doi:<https://doi.org/10.1016/j.sse.2012.01.005>.
- [8] A. M. Grishin, A. A. Velichko, A. Jalalian, Nb_2O_5 nanofiber memristor, *Appl. Phys. Lett.* 103 (2013) 053111. doi:[10.1063/1.4817302](https://doi.org/10.1063/1.4817302).
- [9] C. Nico, T. Monteiro, M. Graa, Niobium oxides and niobates physical properties: Review and prospects, *Prog. Mat. Sci.* 80 (2016) 1–37. doi:[10.1016/j.pmatsci.2016.02.001](https://doi.org/10.1016/j.pmatsci.2016.02.001).
- [10] I. Shindo, H. Komatsu, Growth of $\text{H-Nb}_2\text{O}_5$ single crystals by the floating zone method, *J. Crystal Growth* 34 (1976) 152–153. doi:[10.1016/0022-0248\(76\)90275-X](https://doi.org/10.1016/0022-0248(76)90275-X).
- [11] R. L. Orr, High-temperature heat contents of tantalum and niobium oxides, *J. Amer. Chem. Soc.* 75 (1953) 2808–2809. doi:[10.1021/ja01108a005](https://doi.org/10.1021/ja01108a005).
- [12] E. G. King, Low-temperature heat capacities and entropies at 298.16°K of manganese sesquioxide and niobium pentoxide, *J. Amer. Chem. Soc.* 76 (1954) 3289–3291. doi:[10.1021/ja01641a063](https://doi.org/10.1021/ja01641a063).
- [13] G. Brauer, Die Oxyde des Niobs, *Z. anorg. allg. Chem.* 248 (1941) 1–31. doi:[10.1002/zaac.19412480101](https://doi.org/10.1002/zaac.19412480101).
- [14] H. Schäfer, R. Gruehn, F. Schulte, The modifications of niobium pentoxide, *Angew. Chem., Internat. Ed.* 5 (1966) 40–52. doi:[10.1002/anie.196600401](https://doi.org/10.1002/anie.196600401).
- [15] S. Tamura, K. Kato, M. Goto, Single crystals of $\text{T-Nb}_2\text{O}_5$ obtained by slow cooling method under high pressures, *Z. anorg. allg. Chem.* 410 (1974) 313–315. doi:[10.1002/zaac.19744100311](https://doi.org/10.1002/zaac.19744100311).

- [16] K. Kato, S. Tamura, Die Kristallstruktur von $T\text{-Nb}_2\text{O}_5$, *Acta Cryst. B* 31 (1975) 673–677. doi:10.1107/S0567740875003603.
- [17] L. Mestres, M. L. Martínez-Sarrión, O. Castaño, J. Fernández-Urbán, Phase diagram at low temperature of the system $\text{ZrO}_2/\text{Nb}_2\text{O}_5$, *Z. anorg. allg. Chem.* 627 (2001) 294–298. doi:10.1002/1521-3749(200102)627:2;294::AID-ZAAC294;3.0.CO;2-X.
- [18] B. Pilarek, A. J. Pelczarska, I. Szczygieł, Characterization of niobium(V) oxide received from different sources, *J. Therm. Anal. Calor.* 130 (2017) 77–83.
- [19] M. W. Shafer, R. Rustum, The polymorphism of Nb_2O_5 , *Z. Krist. – Crystalline Materials* 110 (1958) 241–248. doi:10.1524/zkri.1958.110.16.241.
- [20] H. Schadow, H. Oppermann, O. Grossmann, K. Krzewska, B. Wehner, Investigations concerning the quasi-binary system $\text{V}_2\text{O}_5\text{-Nb}_2\text{O}_5$, *Cryst. Res. Technol.* 26 (1991) 401–407. doi:10.1002/crat.2170260405.
- [21] F. Holtzberg, A. Reisman, M. Berry, M. Berkenblit, Chemistry of the group VB pentoxides. VI. the polymorphism of Nb_2O_5 , *J. Amer. Chem. Soc.* 79 (1957) 2039–2043. doi:10.1021/ja01566a004.
- [22] www.factsage.com, FactSage 7.1, GTT Technologies, Kaiserstr. 100, 52134 Herzogenrath, Germany (2017).
- [23] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-037-1468 (2017).
- [24] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-027-1003 (2017).
- [25] R. Roth, J. Waring, H. Parker, Temperature-pressure phase relationships in niobium pentoxide, *J. Res. Nat. Bur. Stand.* 77A (1970) 705–711.
- [26] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-025-0922 (2017).
- [27] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-021-1198 (2017).
- [28] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-021-1199 (2017).
- [29] O. Ruff, Arbeiten im Gebiet hoher Temperaturen I. über das Schmelzen und Verdampfen unserer feuerbeständigsten Oxyde im elektrischen Vakuumofen, *Z. anorg. Chem.* 82 (1913) 373–400. doi:10.1002/zaac.19130820131.
- [30] S. Lagergren, A. Magnli, On the Tantalum – Oxygen System, *Acta Chem. Scand.* 6 (1952) 444–446. doi:10.3891/acta.chem.scand.06-0444.
- [31] R. Roth, J. Waring, H. Parker, Effect of oxide additions on the polymorphism of tantalum pentoxide. IV. The system $\text{Ta}_2\text{O}_5\text{-Ta}_2\text{WO}_8$, *J. Sol. State Chem.* 2 (1970) 445–461. doi:10.1016/0022-4596(70)90104-0.
- [32] E. Füglein, R. Hock, Untersuchungen zur Polymorphie des Tantaloxids Ta_2O_5 , *Z. anorg. allg. Chem.* 628 (2002) 2154–2154. doi:10.1002/1521-3749(200209)628:9/10;2154::AID-ZAAC2154;3.0.CO;2-0.

- [33] H.-U. Hummel, R. Fackler, P. Remmert, Tantaloxide durch Gasphasenhydrolyse, Druckhydrolyse und Transportreaktion aus 2H-TaS₂: Synthesen von TT-Ta₂O₅ und T-Ta₂O₅ und Kristallstruktur von T-Ta₂O₅, *Chem. Ber.* 125 (1992) 551–556. doi:10.1002/cber.19921250304.
- [34] S. P. Garg, N. Krishnamurthy, A. Awasthi, M. Venkatraman, The O–Ta (oxygen–tantalum) system, *J. Phase Equilib.* 17 (1996) 63–77. doi:10.1007/BF02648373.
- [35] J. L. Waring, R. S. Roth, Phase equilibria in the system vanadium oxide–niobium oxide, *J. Res. Natl. Bur. Std. Vol.* 69A. doi:10.6028/jres.069A.014.
- [36] H. Schadow, H. Oppermann, O. Grossmann, Investigations on the quasi-binary subsystem VNb₉O₂₅–Nb₂O₅, *Cryst. Res. Technol.* 27 (1992) 835–838. doi:10.1002/crat.2170270618.
- [37] A. Polte, H. Langbein, Zur Bildung und Umwandlung von Oxidphasen im quasi-binären System V₂O₅–Nb₂O₅, *Z. anorg. allg. Chem.* 620 (1994) 1947–1952. doi:10.1002/zaac.19946201119.
- [38] L. L. Surat, M. G. Zuev, Phase formation in the V₂O₅–Nb₂O₅–MoO₃ system, *Russ. J. Inorg. Chem.* 52 (2007) 1617–1619. doi:10.1134/S0036023607100245.
- [39] P. Tabero, E. Filipek, M. Piz, Reactivity of T-Nb₂O₅ or H-Nb₂O₅ towards V₂O₅. Synthesis in the solid state and properties of V₄Nb₁₈O₅₅, *Central Europ. J. Chem.* 7 (2009) 222–227. doi:10.2478/s11532-009-0001-7.
- [40] O. Redlich, A. T. Kister, Algebraic representation of thermodynamic properties and the classification of solutions, *Industrial & Engineering Chemistry* 40 (1948) 345–348. doi:10.1021/ie50458a036.
- [41] D. Klimm, Phase Equilibria, in: T. Nishinaga (Ed.), *Handbook of Crystal Growth*, Elsevier, 2014, pp. 85–136.
- [42] F. Holtzberg, A. Reisman, Sub-solidus equilibria in the system Nb₂O₅–Ta₂O₅, *J. Phys. Chem.* 65 (1961) 1192–1196. doi:10.1021/j100825a024.
- [43] G. P. Mohanty, L. J. Fiegel, J. H. Healy, On the system niobium pentoxide–tantalum pentoxide, *J. Phys. Chem.* 68 (1964) 208–210. doi:10.1021/j100783a507.
- [44] A. Benrath, F. Gjedebo, B. Schiffers, H. Wunderlich, Über die Löslichkeit von Salzen und Salzgemischen in Wasser bei Temperaturen oberhalb von 100 °C, *Z. anorg. allg. Chem.* 231 (1937) 285–297. doi:10.1002/zaac.19372310308.
- [45] G. P. Mohanty, L. J. Fiegel, J. H. Healy, Unit cell and space group of 2Nb₂O₅·Ta₂O₅, *Acta Cryst.* 15 (1962) 1190. doi:10.1107/S0365110X62003151.
- [46] R. A. Brown, Theory of transport processes in single crystal growth from the melt, *AICHe Journal* 34 (1988) 881–911. doi:10.1002/aic.690340602.
- [47] Z. Li, L. Liu, Y. Zhang, G. Zhou, Influence of crucible thermal conductivity on crystal growth in an industrial directional solidification process for silicon ingots, *Internat. J. Photoenergy* 2016 (2016) 8032709 (9 pages). doi:10.1155/2016/8032709.
- [48] N. Wizent, Hochdruckkristallzüchtung ausgewählter Oxidverbindungen, Ph.D. thesis, Technische Universität Dresden (2009).
- [49] The International Centre for Diffraction Data, <http://www.icdd.com/>, entry 00-049-0289 (2017).

Appendix A. Supplementary Materials

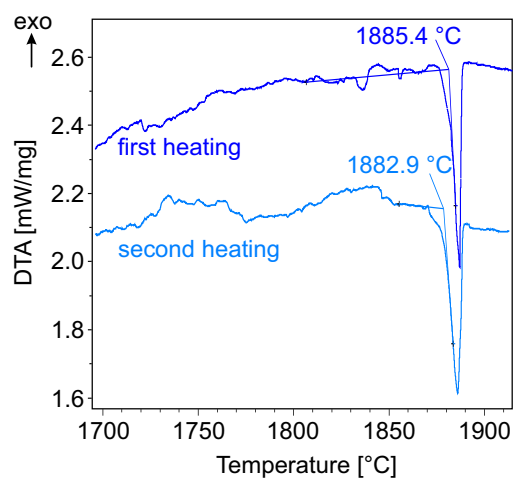


Figure A.1: High-temperature DTA heating curves of a measurement cycle with two heating segments for the determination of the melting point of Ta₂O₅. The temperature at which a phase transition occurs can be determined as the onset of the signals.

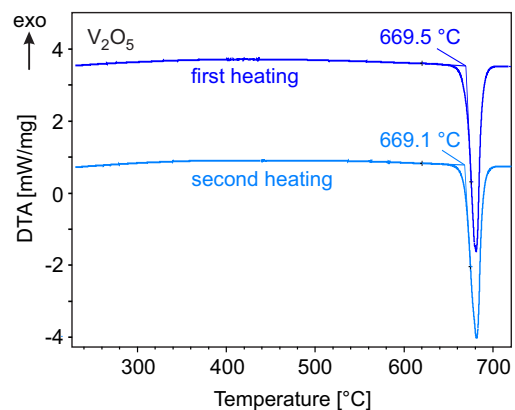


Figure A.2: DTA heating curves of a measurement cycle with two heating segments for the determination of the melting point of V₂O₅. The temperature at which a phase transition occurs can be determined as the onset of the signals.

Table A.1: Thermodynamic parameters of the FactSage simulation for the pure oxides in their solid phases S1 and S2 and their liquid Phase L1: standard enthalpy of formation ΔH and standard entropy S .

	Ta_2O_5		Nb_2O_5		V_2O_5	
	ΔH [J/mol]	S [J/molK]	ΔH [J/mol]	S [J/molK]	ΔH [J/mol]	S [J/molK]
S1	-2045976	143.114	-1899536	137.298	-1550590	130.549
S2	-2061517	111.026	-1897536	139.162	–	–
L1	-1960862	178.959	-1827201	175.256	-1491202	191.958

Table A.2: Thermodynamic parameters of the FactSage simulation for the intermediate compounds: standard enthalpy of formation ΔH and standard entropy S . S1 and S2 denote the two solid phases.

	$\text{V}_2\text{Nb}_9\text{O}_{25}$		$\text{Ta}_2\text{Nb}_4\text{O}_{15}$	
	ΔH [J/mol]	S [J/molK]	ΔH [J/mol]	S [J/molK]
S1	-9359107	694.116	-5843789	401.62
S2	-9343180	733.616	-5834419	399.09

Table A.3: Heat capacity (in J/molK) of the intermediate compound $\text{Ta}_2\text{Nb}_4\text{O}_{15}$ as a function of temperature $c_p = a + b \cdot T + c \cdot T^{-2} + d \cdot T^2$. The two solid phases are denoted by S1 and S2, respectively.

	a	b	c	d
S1	582.44	0.048636	-15231176.17	-6.70E-06
S2	562.44	0.048636	-15231176.17	-6.70E-06

Table A.4: Temperature-dependent interaction parameters for G^{ex} according to eqn. (1) for the simulation of the binary system Nb_2O_5 - Ta_2O_5 .

j	α - Ta_2O_5	β - Ta_2O_5	H- Nb_2O_5	Liquid
0	$5000 + 3 \cdot T$	$5100 + 2.9 \cdot T$	$3800 + 4.6 \cdot T$	$-20000 - 5.6 \cdot T$
1	$12000 + 2.4 \cdot T$	$12000 + 2.2 \cdot T$	$-9500 + 4.4 \cdot T$	$3500 - 2.5 \cdot T$

Table A.5: Temperature-dependent interaction parameters for G^{ex} according to eqn. (1) for the simulation of the binary system Nb_2O_5 - V_2O_5 .

j	H- Nb_2O_5	Liquid
0	$55000 - 34.5 \cdot T$	$-23000 - 5.2 \cdot T$
1	$-56000 - 7.2 \cdot T$	$-3000 - 4.2 \cdot T$

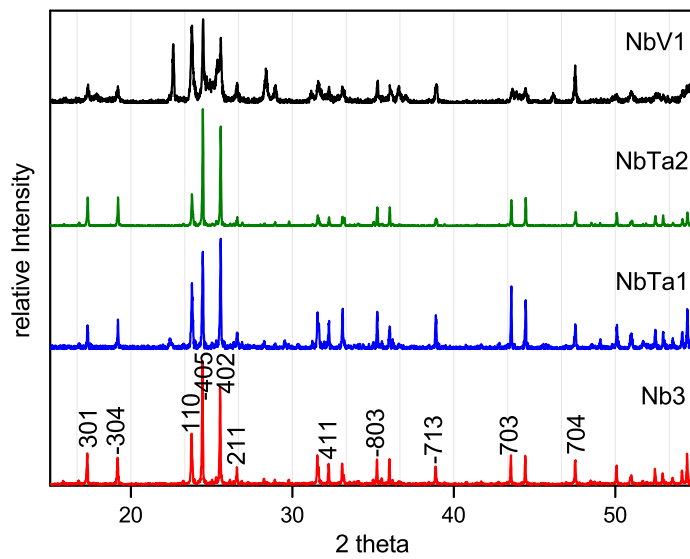


Figure A.3: X-ray diffraction of the samples NbTa1, NbTa2 and NbV1. All diffractograms show the monoclinic H-modification of niobium(V)-oxide.

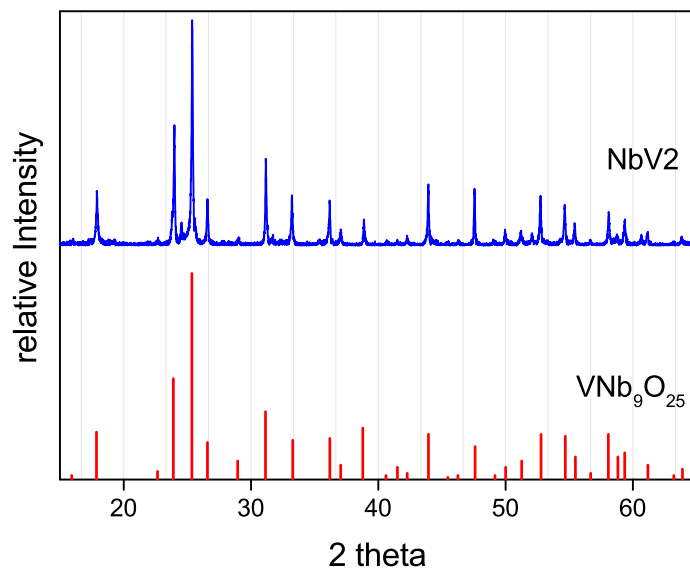


Figure A.4: X-ray diffractogram of the sample NbV2. All occurring reflexes can be assigned to the intermediate compound $\text{VNb}_9\text{O}_{25}$ [49].